SBA-4086

SBA-4086Z

RoHS Compliant & Green Package

DC-5 GHz, Cascadable InGaP/GaAs HBT MMIC Amplifier

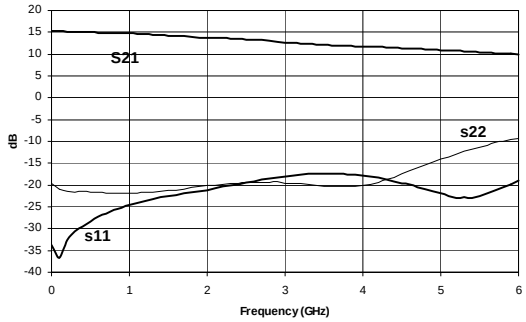


Product Description

Sirenza Microdevices' SBA-4086 is a high performance InGaP/GaAs Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration designed with InGaP process technology provides broadband performance up to 5 GHz with excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only a single positive supply voltage, DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.

The matte tin finish on Sirenza's lead-free package utilizes a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. This package is also manufactured with green molding compounds that contain no antimony trioxide nor halogenated fire retardants.

Gain and Return Loss vs Frequency



Product Features

- **Now available in Lead Free, RoHS Compliant, & Green Packaging**
- **IP3 = 33.5dBm @ 1950MHz**
- **Pout=12.3dBm @-45dBc ACP IS-95 1950MHz**
- **Robust 1000V ESD, Class 1C**
- **Operates From Single Supply**
- **Patented Thermal Design**

Applications

- **PA Driver Amplifier**
- **Cellular, PCS, GSM, UMTS**
- **IF Amplifier**
- **Wireless Data, Satellite Terminals**

Symbol	Parameter	Units	Frequency	Min.	Typ.	Max.
G	Small Signal Gain	dB	850 MHz 1950 MHz	13.3 12.7	14.8 14.2	16.3 15.7
P_{1dB}	Output Power at 1dB Compression	dBm	850 MHz 1950 MHz	 17.5	19.1 19.0	
OIP_3	Output Third Order Intercept Point	dBm	850 MHz 1950 MHz	 31.5	36.5 33.5	
P_{OUT}	Output Power @ -45dBc ACP IS-95 9 Forward Channels	dBm	1950 MHz		12.3	
Bandwidth	Determined by Return Loss (>10dB)	MHz			5000	
IRL	Input Return Loss	dB	1950 MHz	14.0	21.0	
ORL	Output Return Loss	dB	1950 MHz	14.0	20.5	
NF	Noise Figure	dB	1950 MHz		4.8	5.8
V_D	Device Operating Voltage	V		4.6	5.0	5.4
I_D	Device Operating Current	mA		72	80	88
R_{TH}, j-l	Thermal Resistance (junction to lead)	°C/W			102	

Test Conditions: V_S = 8 V, R_{BIAS} = 39 Ohms, I_D = 80 mA Typ., T_L = 25ºC, OIP_3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm, $Z_S = Z_L$ = 50 Ohms

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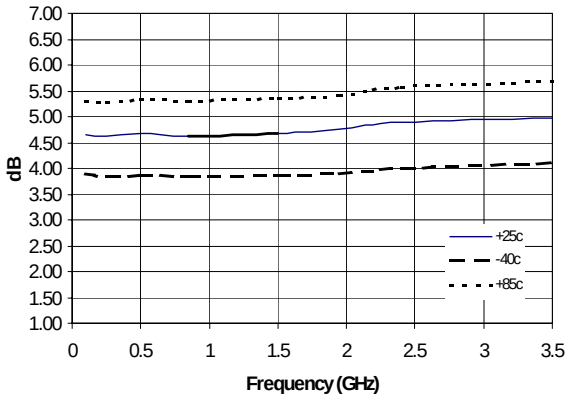
Typical RF Performance at Key Operating Frequencies

Symbol	Parameter	Unit	Frequency (MHz) 100	500	850	1950	2400	3500
G	Small Signal Gain	dB	15.2	15.0	14.8	14.2	12.4	12.1
OIP_3	Output Third Order Intercept Point	dBm	37.1	36.3	36.5	33.5	32.7	29.7
P_{1dB}	Output Power at 1dB Compression	dBm	19.0	19.1	19.1	19.0	18.3	16.4
IRL	Input Return Loss	dB	36	28	25	21	19.7	17
ORL	Output Return Loss	dB	21	21	21.0	20.5	19.6	20.2
S_{12}	Reverse Isolation	dB	18	18	18	18	19	20
NF	Noise Figure	dB	4.7	4.7	4.6	4.8	4.9	5.0

Test Conditions: V_S = 8 V, R_{BIAS} = 39 Ohms, I_D = 80 mA Typ., T_L = 25ºC, OIP_3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm, $Z_S = Z_L$ = 50 Ohms

NF vs Frequency



Absolute Maximum Ratings

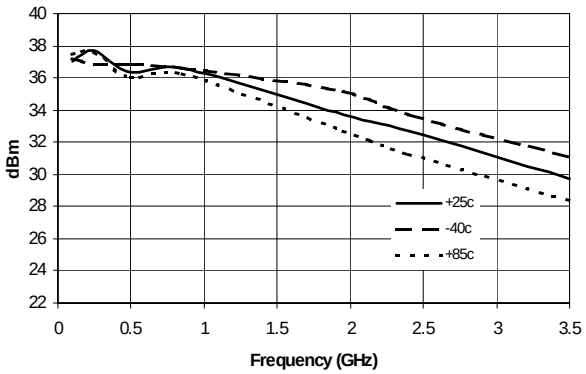
Parameter	Absolute Limit
Max. Device Current (I_D)	130 mA
Max. Device Voltage (V_D)	6 V
Max. RF Input Power	+17 dBm
Max Operating Dissipated Power	0.65 W
Max. Junction Temp. (T_J)	+150°C
Operating Temp. Range (T_L)	-40°C to +85°C
Max. Storage Temp.	+150°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

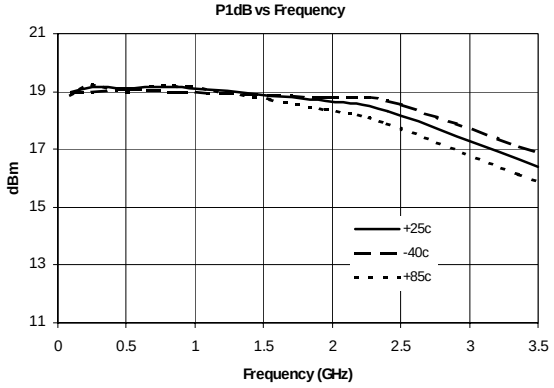
Bias Conditions should also satisfy the following expression:

$I_D V_D < (T_J - T_L) / R_{TH, j-l}$ $T_L = T_{LEAD}$

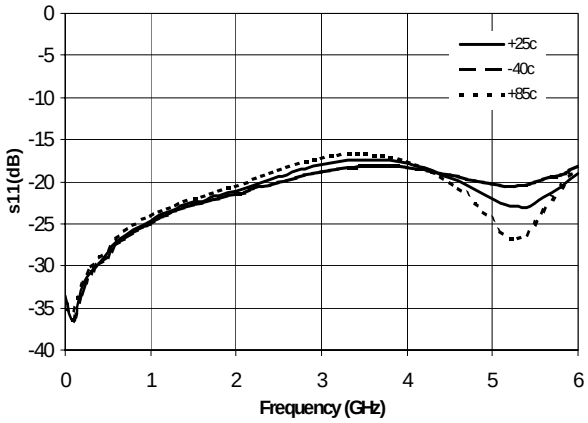
IP3 vs Frequency



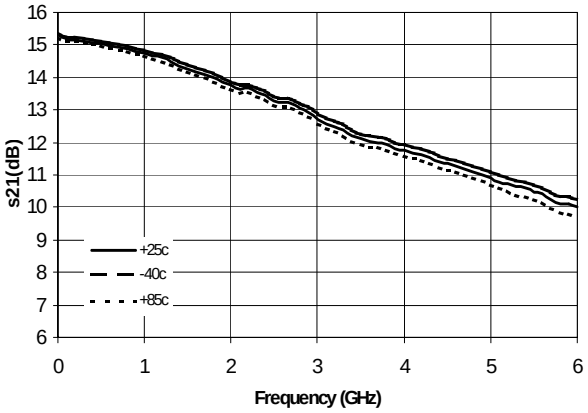
P1dB vs Frequency



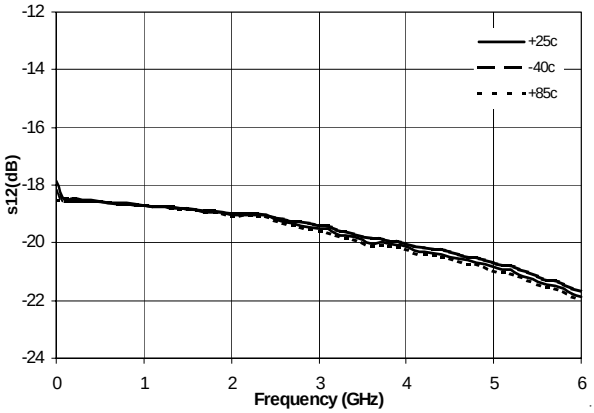
|S11| vs. Frequency



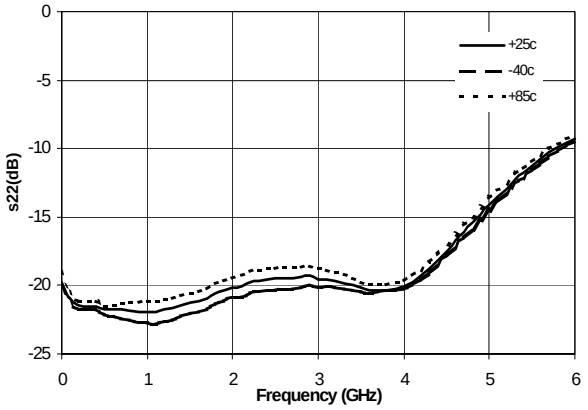
|S21| vs. Frequency



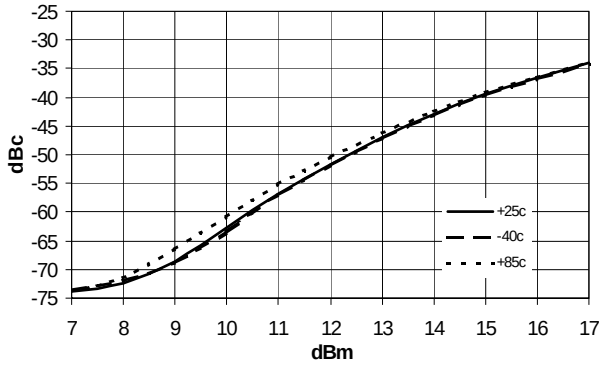
|S12| vs. Frequency



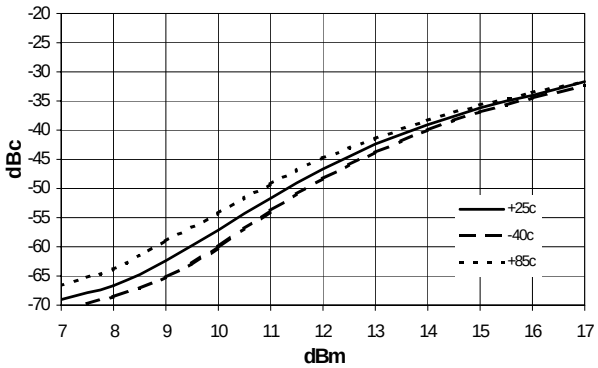
|S22| vs. Frequency



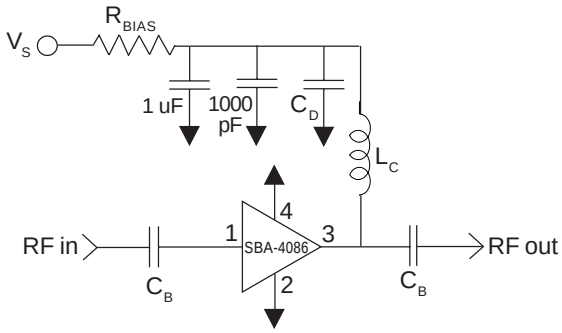
SBA-4086 IS-95 @ 850MHz
Adj. Channel Pwr. Vs. Channel Output Pwr.

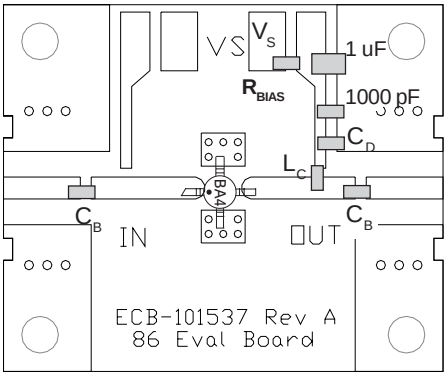


SBA-4086 IS-95 @ 1950MHz
Adj. Channel Pwr. Vs. Channel Output Pwr.



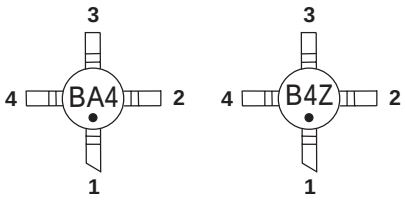
Basic Application Circuit





Part Identification Marking

The part will be marked with an "BA4" or "B4Z" designator on the top surface of the package.



Caution: ESD sensitive
Appropriate precautions in handling, packaging and testing devices must be observed.

Application Circuit Element Values

Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C_B	220 pF	100 pF	68 pF	56 pF	39 pF
C_D	100 pF	68 pF	22 pF	22 pF	15 pF
L_C	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I_D=80mA R_{BIAS}=(V_S-V_D) / I_D				
Supply Voltage(V_S)	7.5 V	8 V	10 V	12 V
R_{BIAS}	33 Ω	39 Ω	68 Ω	91 Ω
Note: R_{BIAS} provides DC bias stability over temperature.				

Mounting Instructions

1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.

2. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

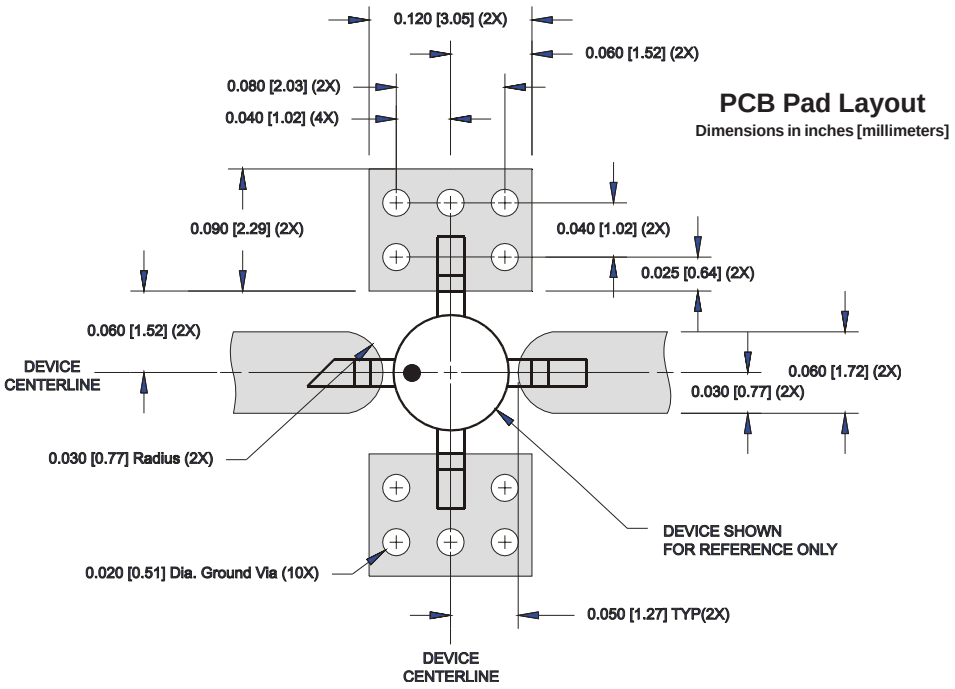
Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SBA-4086	7"	1000
SBA-4086Z	7"	1000

PCB Pad Layout

Dimensions in inches [millimeters]



Nominal Package Dimensions

Dimensions in inches [millimeters]

Refer to drawing posted at *www.sirenza.com* for tolerances.

